

RBE015N10R1SZPV

REXFET-1 N-Channel Power MOSFET

100 V - 340 A - 1.5 m Ω - TOLG

Description

The RBE015N10R1SZPV N-channel power MOSFET features REXFET-1 split-gate technology and is offered in a TOLG package. The TOLG package has a similar profile and footprint to the TOLL package, but with the benefits of gullwing leads for high thermal cycling capability.

Renesas' REXFET-1 split-gate technology is well-suited for applications that require low RDS(on) and switching capability, making it ideal for high-power and high-frequency applications.

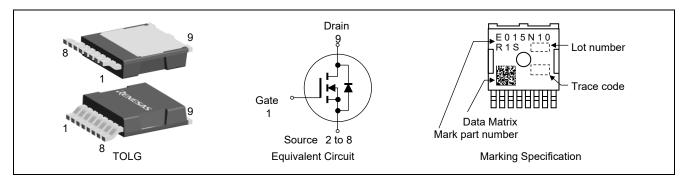
Features

- Standard level gate drive voltage: V_{GS(th)} = 2.0 to 4.0 V
- Super low on-state resistance: $R_{DS(on)} = 1.5 \text{ m}\Omega$ Max.
- Low input capacitance
- · Low thermal resistance
- 100% Avalanche tested
- Pb-free lead plating: RoHS compliant
- MSL1 classified according to IPC/JEDEC J-STD-020

Application

Motor Control, Energy Infrastructure, Industrial Automation, DC-DC Power Conversion, Power Tools, Robotics

Outline



Absolute Maximum Ratings

(Tj = 25 °C unless otherwise notice.)

| Item | Symbol | Ratings | Unit |
|--------------------------------|--------------------------|------------|------|
| Drain to Source Voltage | V _{DSS} | 100 | V |
| Gate to Source Voltage | V _{GSS} | ±20 | V |
| Drain Current (DC) | ID(DC) Tc=25°C Note 2,6 | ±340 | А |
| | ID(DC) Tc=100°C Note 2,6 | ±272 | А |
| Drain Current (pulse) | ID(pulse) Note 1,3,6 | ±1360 | А |
| Power Dissipation | P _D Note 1,6 | 468 | W |
| Operating Junction Temperature | Tj | -55 to 175 | °C |
| Storage Temperature | T _{stg} | -55 to 175 | °C |
| Single Avalanche Current | IAS Note 4 | 64 | А |
| Single Avalanche Energy | Eas Note 4 | 409 | mJ |

Thermal Resistance

| Item | Symbol | Max. | Unit |
|--|-------------------|------|------|
| Junction to Case Thermal Resistance | Rth(j-c) Note 6 | 0.32 | °C/W |
| Junction to Ambient Thermal Resistance | Rth(j-a) Note 5,6 | 40 | °C/W |

Electrical Characteristics

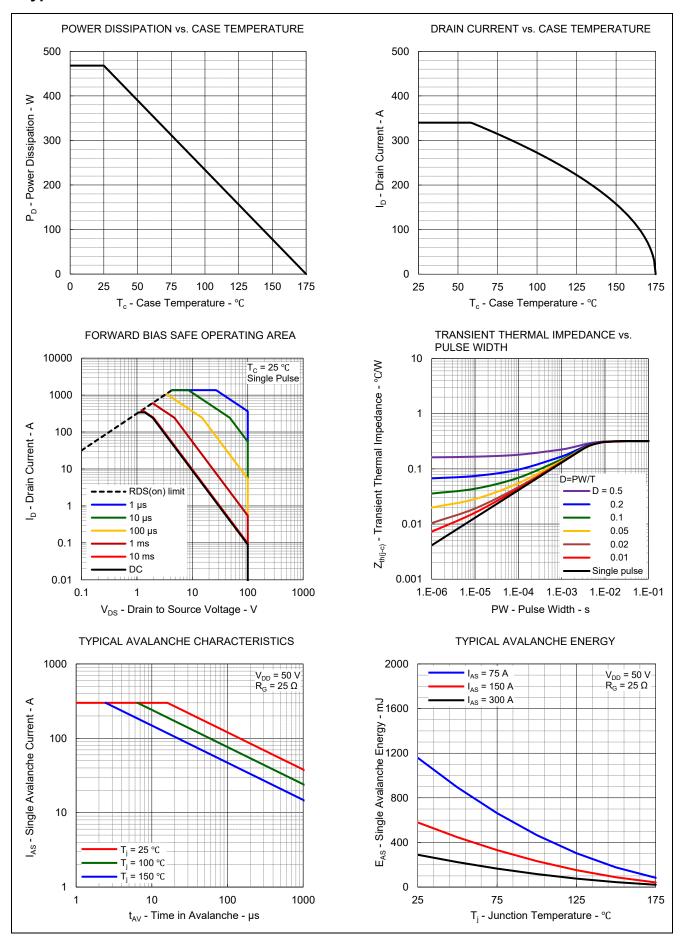
 $(T_j = 25 \, ^{\circ}\text{C} \text{ unless otherwise notice.})$

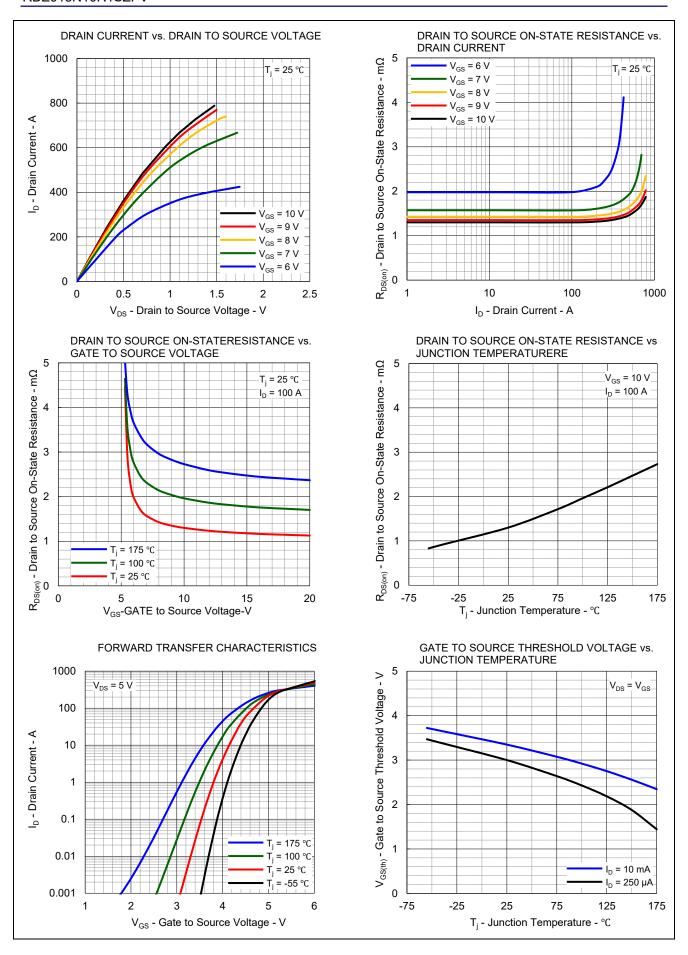
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|-------------------------------------|----------------------|-----|-------|------|------|---|
| Zero Gate Voltage Drain Current | I _{DSS} | _ | _ | 10 | μA | V _{DS} = 100 V, V _{GS} = 0 V |
| Gate Leakage Current | I _{GSS} | _ | _ | ±100 | nA | V_{GS} = \pm 20 V , V_{DS} = 0 V |
| Gate to Source Threshold Voltage | $V_{GS(th)}$ | 2.0 | _ | 4.0 | V | V_{DS} = V_{GS} , I_D = 250 μ A |
| Drain to Source On-state Resistance | R _{DS(on)} | _ | 1.3 | 1.5 | mΩ | V _G S = 10 V, I _D = 100 A |
| Input Capacitance | C _{iss} | _ | 13000 | _ | pF | V _{DS} = 50 V |
| Output Capacitance | C _{oss} | _ | 3300 | _ | pF | $V_{GS} = 0 V$ |
| Reverse Transfer Capacitance | C _{rss} | _ | 80 | _ | pF | f = 100 kHz |
| Gate resistance | R _g | _ | 1.8 | _ | Ω | _ |
| Turn-on Delay Time | t _{d(on)} | _ | 75 | _ | ns | V _{DD} = 50 V |
| Rise Time | t _r | _ | 60 | _ | ns | I _D = 100 A |
| Turn-off Delay Time | t _{d(off)} | _ | 130 | _ | ns | V _{GS} = 10 V |
| Fall Time | t _f | _ | 55 | _ | ns | $R_G = 5 \Omega$ |
| Total Gate Charge | Q _g | _ | 170 | _ | nC | V _{DD} = 50 V |
| Gate to Source Charge | Q_{gs} | _ | 75 | _ | nC | V _{GS} = 10 V |
| Gate to Drain Charge | Q_{gd} | _ | 30 | _ | nC | I _D = 100 A |
| Gate plateau voltage | V _{plateau} | _ | 5.4 | _ | V | |
| Output Charge | Q _{oss} | _ | 280 | _ | nC | V _{DD} = 50 V, V _{GS} = 0 V |
| Body Diode Forward Voltage | $V_{F(S-D)}$ | _ | 0.85 | 1.5 | V | I _F = 100 A, V _{GS} = 0 V |
| Reverse Recovery Time | t _{rr} | _ | 110 | _ | ns | I _F = 100 A, V _{GS} = 0 V |
| Reverse Recovery Charge | Q _{rr} | _ | 300 | _ | nC | di/dt = 100 A/µs |

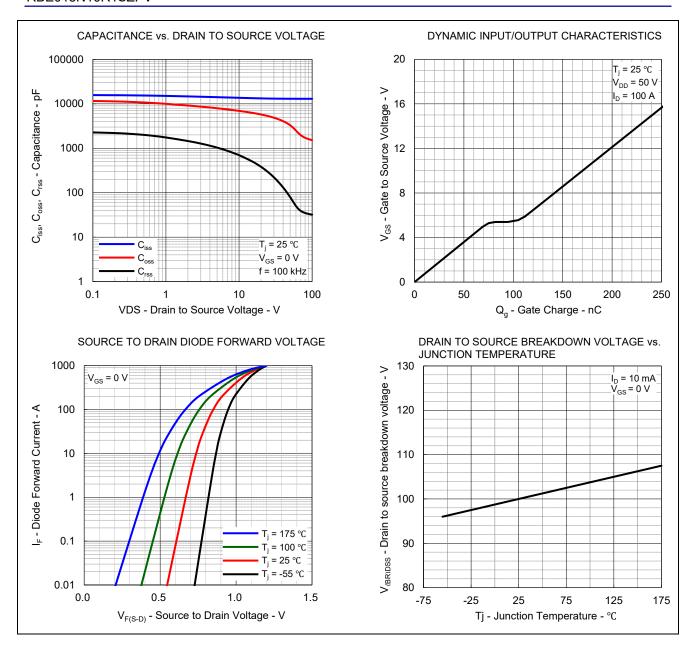
Note 1. T_c = 25 °C

- 2. Value is limited by overall system design including PCB.
- 3. PW ≤ 10 μ s
- 4. L = 100 μ H, V_{DD} = 50 V, R_G = 25 Ω
- 5. Device on 40 mm x 40 mm x 1.5 mm epoxy PCB FR4. (2 oz Cu pad.)
- 6. Defined by design. Not subject to production test.

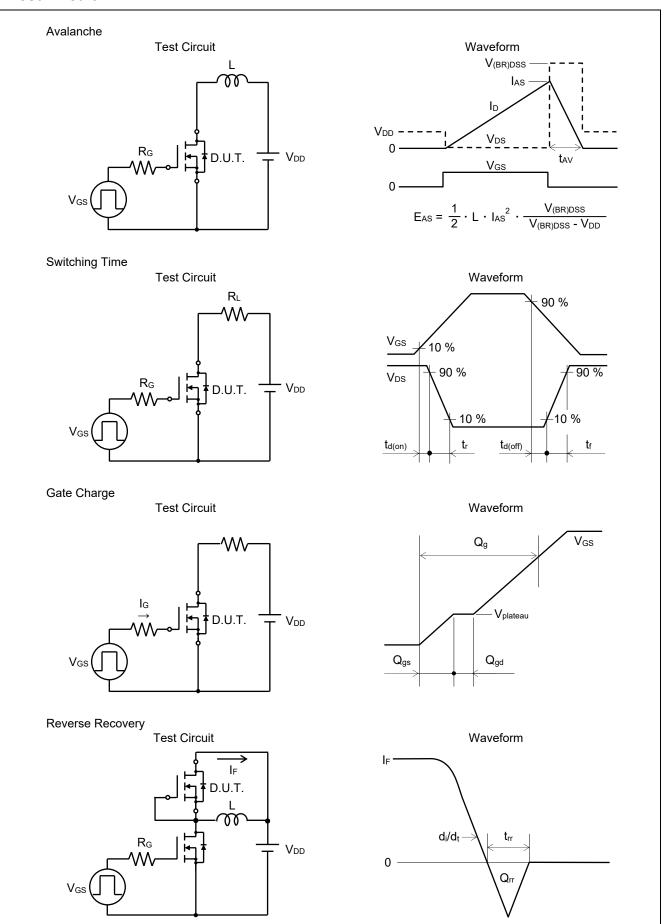
Typical Characteristics



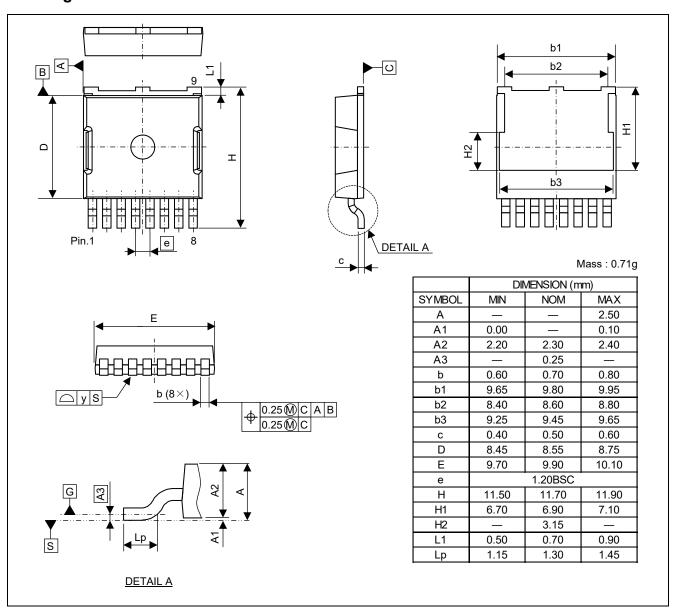




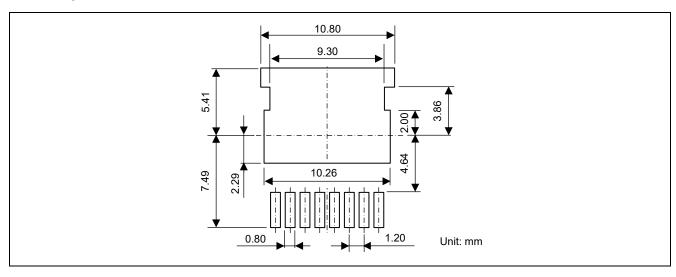
Test Circuit



Package Dimensions



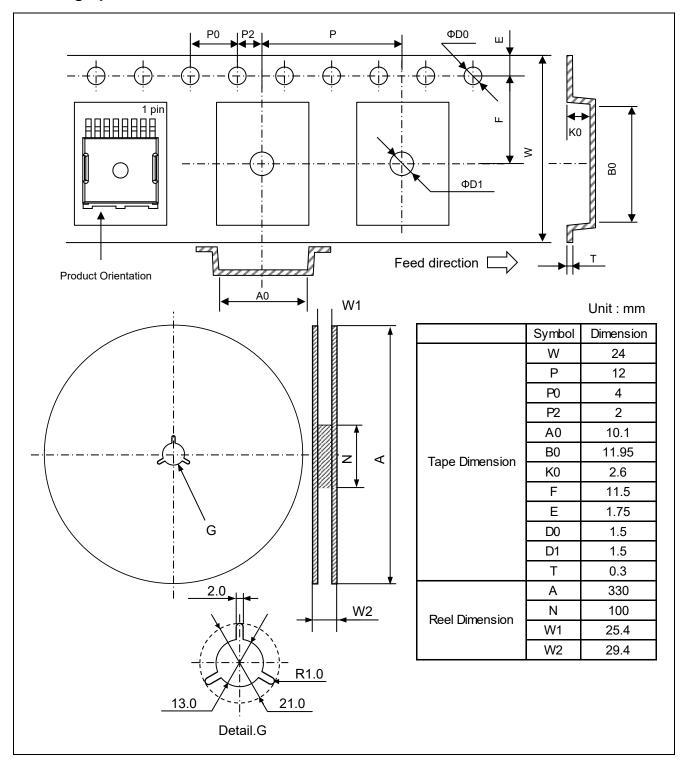
Mount pad



Ordering Information

| Part No. | Packing | Quantity |
|---------------------|---------|--------------|
| RBE015N10R1SZPV#GB0 | Taping | 1500pcs/reel |

Packing Specification



Remark: Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

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